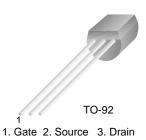
September 2007



# J305 N-Channel RF Amplifier

• This device is designed primarily for electronic switching applications such as low on resistance analog switching.

• Sourced from process 50.



## Absolute Maximum Ratings\* $T_a=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>DG</sub>	Drain-Gate Voltage	30	V
V <sub>GS</sub>	Gate-Source Voltage	-30	V
I <sub>GF</sub> Forward Gate Current 10		mA	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

\* This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1) These rating are based on a maximum junction temperature of 150 degrees C.

2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Max.	Units	
PD	Total Device Dissipation	350	mW	
_	Derate above 25°C	2.8	mW/°C	
R <sub>0JC</sub>	R <sub>θJC</sub> Thermal Resistance, Junction to Case 125		°C/W	
R <sub>0JA</sub>	A Thermal Resistance, Junction to Ambient 357		°C/W	

### Electrical Characteristics\* Ta=25°C unless otherwise noted

	a				
Symbol	Parameter	Test Condition	Min.	Max.	Units

#### **Off Characteristics**

V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$I_{G} = 1.0 \mu A, V_{DS} = 0$	-30		V
I <sub>GSS</sub>	Gate Reverse Current	$V_{GS} = 20V, V_{DS} = 0$		-100	pА
V <sub>GS(off)</sub>	Gate-Source Cut-off Voltage	V <sub>DS</sub> = 15V, I <sub>D</sub> = 100nA	-0.5	-3	V
V <sub>GS</sub>	Gate-Source Forward Voltage	$V_{DS} = 15V, I_{D} = 0.2mA$	-1.5	-4.0	V

#### **On Characteristics**

*IDSSZero-Gate Voltage Drain Current * $V_{DS} = 15V$ , $V_{GS} = 0$ 18mA
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#### **Small Signal Characteristics**

<b>g</b> fs	Forward Transferconductance	$V_{DS} = 15V, V_{GS} = 0V$	3000	μ/Ω
* Pulse Test: Pulse Width ≤ 300µs, Duty Cycle = 2%				



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FPS™ FRFET <sup>®</sup>			-
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